Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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Emitter common (dual digital transistors)

EMG8 / UMG8N / FMG8A

●**Features**

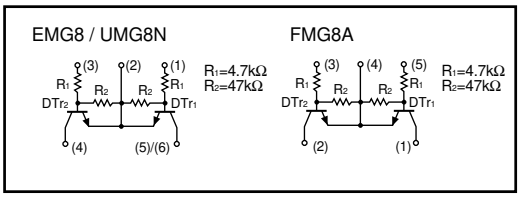
1) Two DTC143Z chips in a EMT or UMT or SMT package.
2) Mounting cost and area can be cut in half.

●**Structure**

Epitaxial planar type
NPN silicon transistor
(Built-in resistor type)

The following characteristics apply to both the DTr_1 and DTr_2.

●**Equivalent circuit**



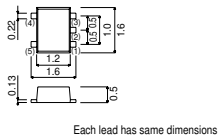
●**Absolute maximum ratings** (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Supply voltage		V_{CC}	50	V
Input voltage		V_{IN}	30	V
			−5	
Output current		I_O	100	mA
		$I_{C\ (Max.)}$	100	
Power dissipation	EMG8, UMG8N	Pd	150 (TOTAL)	mW ∗1
	FMG8A		300 (TOTAL)	∗2
Junction temperature		Tj	150	˚C
Storage temperature		Tstg	−55~+150	˚C

∗1 120mW per element must not be exceeded.
∗2 200mW per element must not be exceeded.

●**External dimensions** (Units : mm)

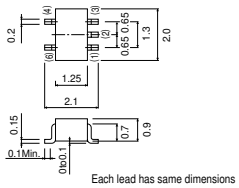
EMG8



ROHM : EMT5

Abbreviated symbol : G8

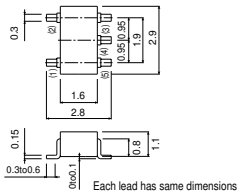
UMG8N



ROHM : UMT5
EIAJ : SC-88A

Abbreviated symbol : G8

FMG8A



ROHM : SMT5
EIAJ : SC-74A

Abbreviated symbol : G8

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	–	–	0.5	V	V_{CC}=5V, I_O=100μA
	$V_{I(on)}$	1.3	–	–		V_O=0.3V, I_O=5mA
Output voltage	$V_{O(on)}$	–	0.1	0.3	V	I_O=5mA, I_I=0.25mA
Input current	I_I	–	–	1.8	mA	V_I=5V
Output current	$I_{O(off)}$	–	–	0.5	μA	V_{CC}=50V, V_I=0V
DC current gain	G_I	80	–	–	–	V_O=5V, I_O=10mA
Transition frequency	f_T	–	250	–	MHz	V_{CE}=10mA, I_E=–5mA, f=100MHz *
Input resistance	R_1	3.29	4.7	6.11	kΩ	–
Resistance ratio	R_2/R_1	8	10	12	–	–

* Transition frequency of the device

●Packaging specifications

Type	Package	Taping		
	Code	T2R	TR	T148
	Basic ordering unit (pieces)	8000	3000	3000
EMG8		○	—	—
UMG8N		—	○	—
FMG8A		—	—	○

●Electrical characteristic curves

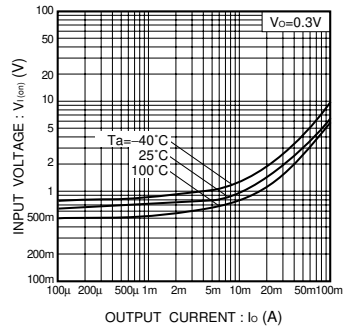


Fig.1 Input voltage vs. output current (ON characteristics)

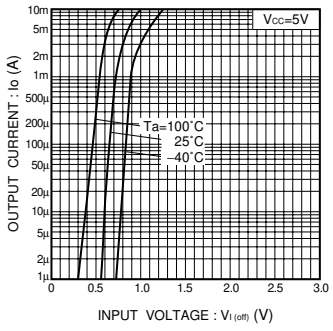


Fig.2 Output current vs. input voltage (OFF characteristics)

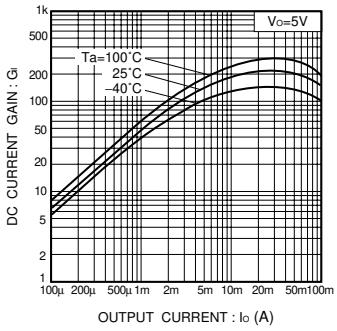


Fig.3 DC current gain vs. output current

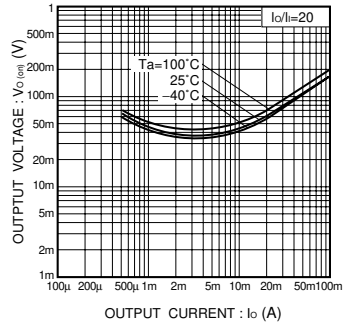


Fig.4 Output voltage vs. output current